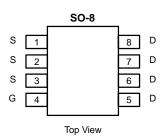


# N-Channel 30-V (D-S) MOSFET with Schottky Diode

MOSFET PRODUCT SUMMARY				
V <sub>DS</sub> (V)	I <sub>D</sub> (A)			
30	0.0135 @ V <sub>GS</sub> = 10 V	10		
	0.020 @ V <sub>GS</sub> = 4.5 V	8		

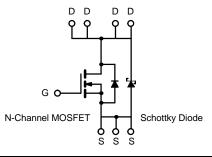
SCHOTTKY PRODUCT SUMMARY			
V <sub>SD</sub> (V) V <sub>DS</sub> (V) Diode Forward Voltage		I <sub>F</sub> (A)	
30	0.53 V @ 3.0 A	4.0	



Ordering Information:

Si4810DY Si4810DY-T1 (with Tape and Reel)





### ABSOLUTE MAXIMUM RATINGS (TA = 25°C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage (MOSFET)		N	30	
Reverse Voltage (Schottky)		V <sub>DS</sub>	30	V
Gate-Source Voltage (MOSFET)		V <sub>GS</sub>	±20	
Continuous Drain Current (T <sub>J</sub> = 150°C) (MOSFET) <sup>a, b</sup>	$T_A = 25^{\circ}C$	I <sub>D</sub>	10	
	$T_A = 70^{\circ}C$	- טי	8	
Pulsed Drain Current (MOSFET)		I <sub>DM</sub>	50	A
Continuous Source Current (MOSFET Diode Conduction) <sup>a, b</sup>		ا <sub>S</sub>	2.3	
Average Foward Current (Schottky)		I <sub>F</sub>	4.0	
Pulsed Foward Current (Schottky)		I <sub>FM</sub>	50	
Movimum Dever Dissignation (MOSEET)a b	$T_A = 25^{\circ}C$		2.5	
Maximum Power Dissipation (MOSFET) <sup>a, b</sup>	T <sub>A</sub> = 70°C		1.6	w
Maximum Power Dissipation (Schottky) <sup>a, b</sup>	$T_A = 25^{\circ}C$	• • • • • • • • • • • • • • • • • • •	2.0	VV
	$T_A = 70^{\circ}C$	1	1.3	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter	Device	Symbol	Typical	Maximum	Unit
	MOSFET	R <sub>thJA</sub>		50	°C/W
Maximum Junction-to-Ambient (t $\leq$ 10 sec) <sup>a</sup>	Schottky			60	
	MOSFET		70		
Maximum Junction-to-Ambient (t = steady state) <sup>a</sup>	Schottky		80		

Notes

a. Surface Mounted on FR4 Board.

b.  $t \leq 10$  sec.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm

# Si4810DY

# Vishay Siliconix



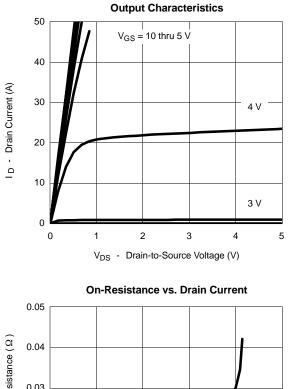
Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit	
Static				•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$ = ±20 V			±100	nA	
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$		0.007	0.100	mA	
Zero Gate Voltage Drain Current (MOSFET + Schottky)	IDSS	$V_{DS}$ = 30 V, $V_{GS}$ = 0 V, $T_J$ = 100°C		1.5	10		
		$V_{DS}$ = 30 V, $V_{GS}$ = 0 V, $T_J$ = 125°C		6.5	20	1	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5$ V, $V_{GS}$ = 10 V	20			А	
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A}$	0.0105 0.013		0.0135		
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 5 \text{ A}$		0.0155	0.020	Ω	
Forward Transconductancea	9fs	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 10 \text{ A}$		28		S	
		$I_{S} = 3.0 \text{ A}, V_{GS} = 0 \text{ V}$	/ <sub>GS</sub> = 0 V		0.53	v	
Schottky Diode Forward Voltagea	V <sub>SD</sub>	$I_{S}$ = 3.0 A, $V_{GS}$ = 0 V, $T_{J}$ = 125 °C		0.420	0.47	v	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			20	30		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = $$ 5 V, $I_{D}$ = 10 A		8		nC	
Gate-Drain Charge	Q <sub>gd</sub>			7		1	
Gate Resistance	Rg		0.5	1.0	1.6	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			15	30		
Rise Time	t <sub>r</sub>	$V_{DD} = 15 V, R_{L} = 15 \Omega$		8	15		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 6 \Omega$		45	90	ns	
Fall Time	t <sub>f</sub>			18	40	1	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 3.0 A, di/dt = 100 A/μs		36	70	1	

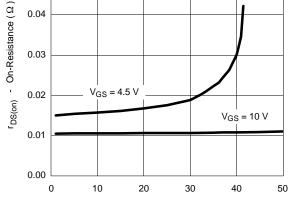
Notes a. Pulse test; pulse width  $\leq 300 \ \mu$ s, duty cycle  $\leq 2\%$ . b. Guaranteed by design, not subject to production testing.



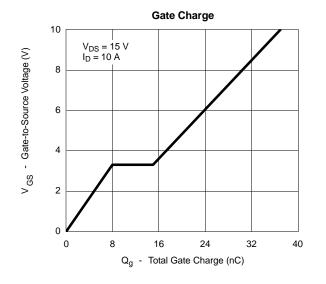
# Si4810DY **Vishay Siliconix**

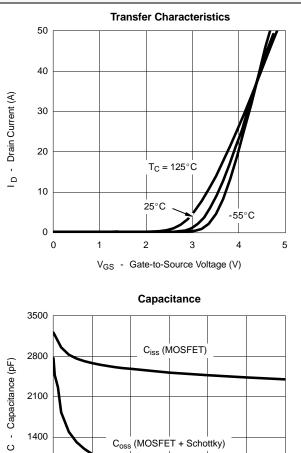
#### **TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**











2100

1400

700

0

0

V<sub>DS</sub> - Drain-to-Source Voltage (V)

15

20

25

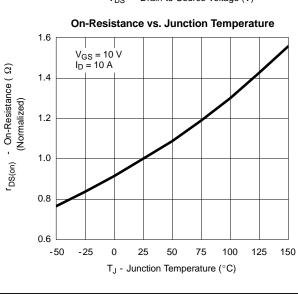
30

Coss (MOSFET + Schottky)

C<sub>rss</sub> (MOSFET)

10

5

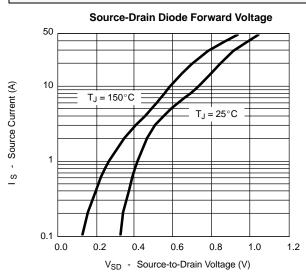


Document Number: 70802 S-31062-Rev. F, 26-May-03

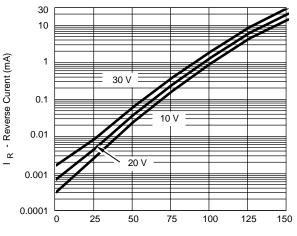
### Si4810DY Vishay Siliconix



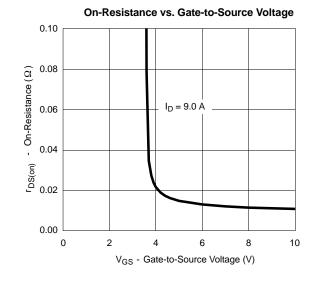
#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



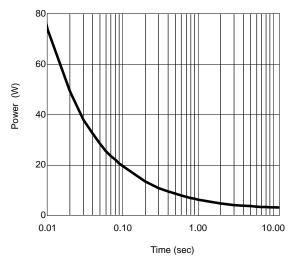
Reverse Current (Schottky)



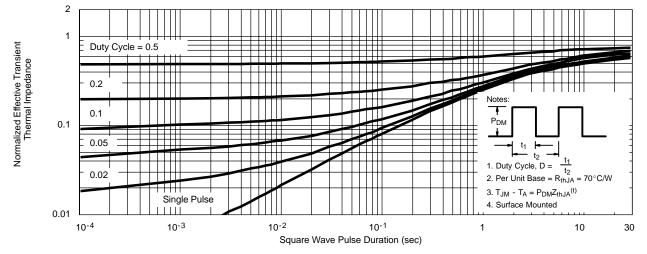
 $T_J$  - Temperature (°C)



Single Pulse Power

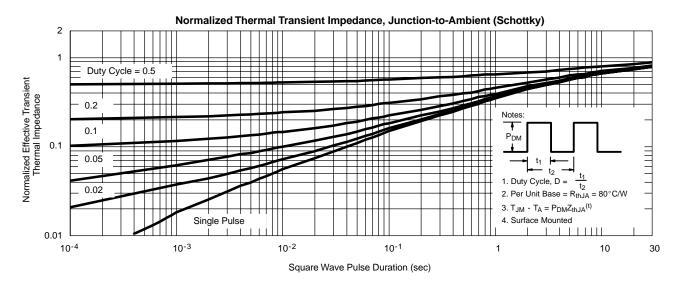


Normalized Thermal Transient Impedance, Junction-to-Ambient











Vishay

# Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

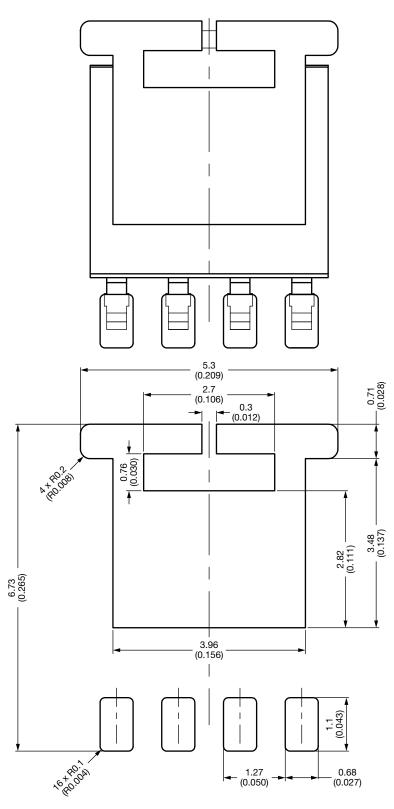
Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.



Vishay Siliconix

# **Recommended Land Pattern PowerPAK® SO-8L Single Short Ear**



Dimensions in Millimeters (Inches)

Revision: 24-Aug-2021

Document Number: 78020



Vishay

### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1